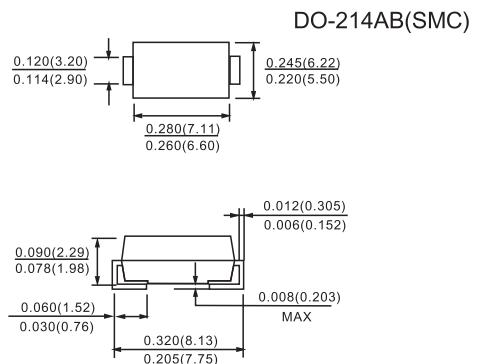


FEATURES

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings

Parameters	30BQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	3.0	A	50% duty cycle @ $T_L = 118^\circ\text{C}$, rectangular wave form
	4.0		50% duty cycle @ $T_L = 110^\circ\text{C}$, rectangular wave form
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current	2000	A	5μs Sine or 3μs Rect. pulse
	110		10ms Sine or 6ms Rect. pulse
E_{AS} Non Repetitive Avalanche Energy	6.0	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 1.0\text{A}$, $L = 12\text{mH}$
I_{AR} Repetitive Avalanche Current	1.0	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_a = 1.5 \times V_r$ typical

Electrical Specifications

Parameters	30BQ	Units	Conditions
V_{FM} Max. Forward Voltage Drop (1)	0.53	V	$@ 3\text{A}$
	0.68	V	$@ 6\text{A}$
	0.43	V	$@ 3\text{A}$
	0.57	V	$@ 6\text{A}$
I_{RM} Max. Reverse Leakage Current (1)	0.5	mA	$T_J = 25^\circ\text{C}$
	30	mA	$T_J = 125^\circ\text{C}$
C_T Max. Junction Capacitance	230	pF	$V_R = 5V_{DC}$ (test signal range 100KHz to 1Mhz) 25°C
L_S Typical Series Inductance	3.0	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change	10000	V/μs	(Rated V_R)

(1) Pulse Width < 300μs, Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	30BQ	Units	Conditions
T_J Max. Junction Temperature Range (*)	-55 to 150	°C	
T_{stg} Max. Storage Temperature Range	-55 to 150	°C	
R_{thJL} Max. Thermal Resistance Junction to Lead (**) (**)	12	°C/W	DC operation
R_{thJA} Max. Thermal Resistance Junction to Ambient	46	°C/W	DC operation
wt Approximate Weight	0.24 (0.008)	g (oz.)	
Case Style	SMC		Similar to DO-214AB
Device Marking	IR3F		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th}(j-a)}$ thermal runaway condition for a diode on its own heatsink

(**) Mounted 1 inch square PCB

RATINGS AND CHARACTERISTIC CURVES 30BQ040

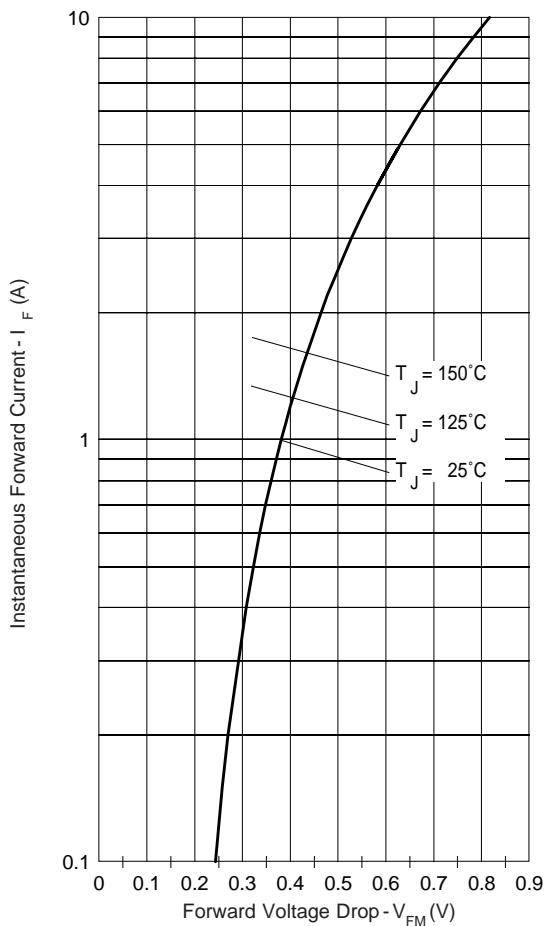


Fig. 1 - Max. Forward Voltage Drop Characteristics (Per Leg)

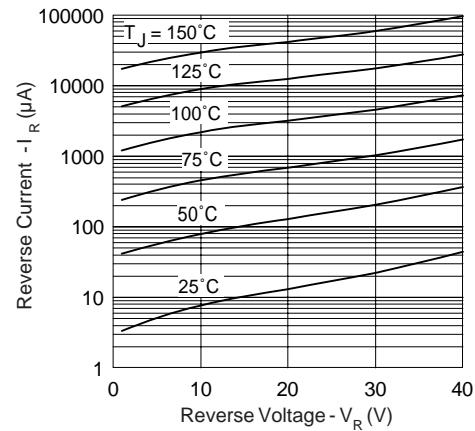


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage (Per Leg)

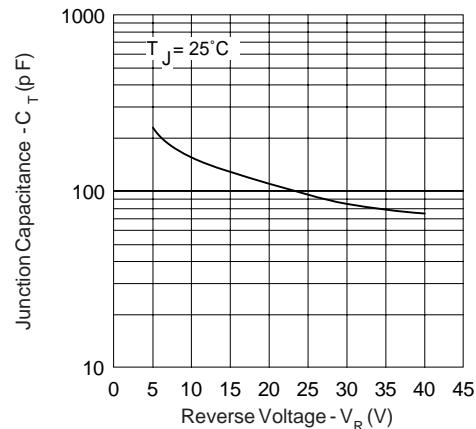


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

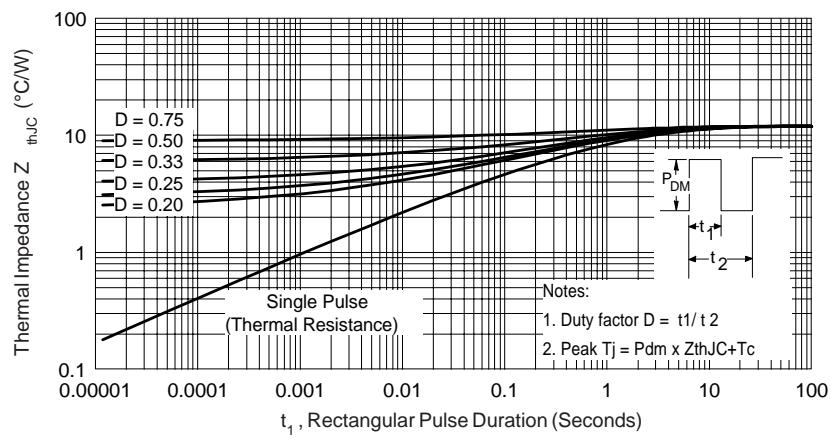


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)

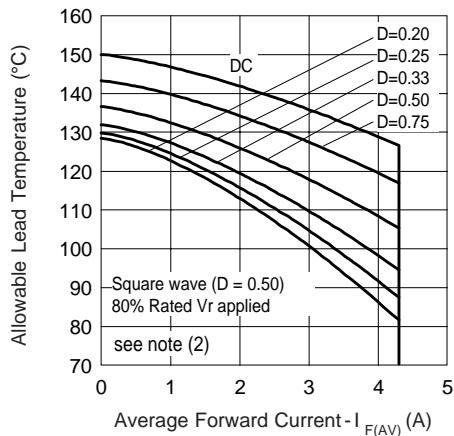


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

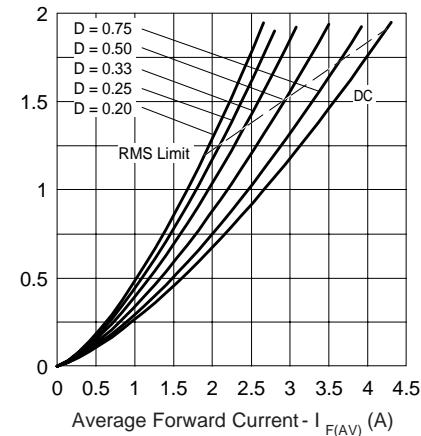


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

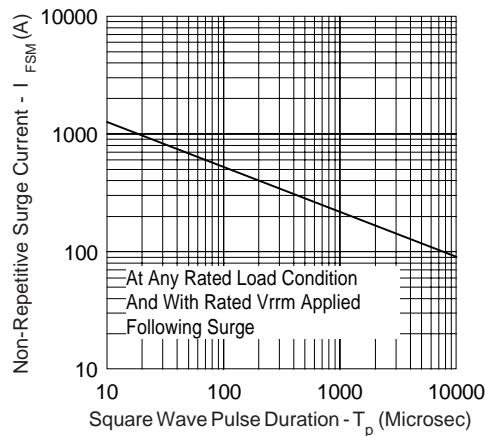


Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

- (2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 $Pd = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $Pd_{REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D); I_R @ V_{R1} = 80\% \text{ rated } V_R$